

Kingtronics®

BTA16 800B

FOUR QUADRANT TRIIACS

Blocking Voltage - 800 Volts On-state RMS Current - 16 Ampere

FEATURES

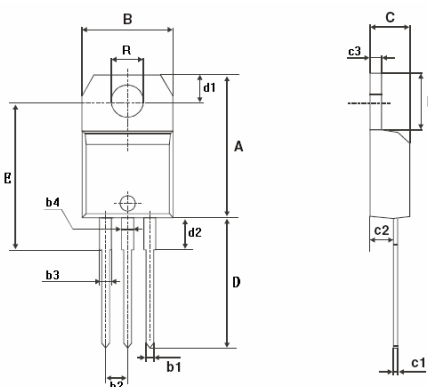
- ◆ Ultra low gate trigger current.
- ◆ Low cost package.

APPLICATIONS

Typical applications include motor control, industrial and domestic lighting, heating and static switching.

- ◆ Heating regulation.
- ◆ Motor control.
- ◆ Phase control.

TO-220





| DIM | Inches | | | Millimeters | | |
|-----|--------|-------|-------|-------------|--------|--------|
| | Min | Type | Max | Min | Type | Max |
| A | 0.591 | - | 0.646 | 15.000 | - | 16.400 |
| B | 0.386 | - | 0.409 | 9.800 | - | 10.400 |
| C | 0.160 | - | 0.190 | 4.070 | - | 4.820 |
| D | 0.500 | - | 0.562 | 12.700 | - | 14.270 |
| E | - | 0.640 | - | - | 16.250 | - |
| F | 0.248 | - | 0.271 | 6.290 | - | 6.890 |
| R | 0.140 | - | 0.156 | 3.560 | - | 3.960 |
| b1 | 0.030 | - | 0.037 | 0.750 | - | 0.950 |
| b2 | 0.095 | - | 0.105 | 2.420 | - | 2.660 |
| b3 | 0.046 | - | 0.054 | 1.170 | - | 1.370 |
| b4 | 0.046 | - | 0.054 | 1.170 | - | 1.370 |
| c1 | 0.017 | - | 0.023 | 0.420 | - | 0.580 |
| c2 | 0.091 | - | 0.115 | 2.320 | - | 2.920 |
| c3 | 0.045 | - | 0.055 | 1.150 | - | 1.390 |
| d1 | 0.100 | - | 0.120 | 2.540 | - | 3.040 |
| d2 | 0.125 | - | 0.155 | 3.180 | - | 3.930 |

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Kingtronics®**BTA16 800B****FOUR QUADRANT TRIIACS****Blocking Voltage - 800 Volts On-state RMS Current - 16 Ampere****PINNING INFORMATION**

| PIN | Description | Simplified outline | Symbol |
|-----|------------------------|--|--|
| 1 | main terminal 1 (T1) |  TO-220 ³ |  |
| 2 | main terminal 2 (T2) | | |
| 3 | gate (G) | | |

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|-----|------|
| V_{DRM} V_{RRM} | Repetitive peak off-state voltages | 800 | V |
| $I_{T(RMS)}$ | RMS on-state current | 16 | A |
| I_{TSM} | Non-repetitive peak on-state current | 120 | A |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------|--|-------------|-----|-----|------|------|
| R_{thj-mb} | Thermal resistance junction to mounting base | full cycle | - | - | 1.50 | K/W |
| | | half cycle | - | - | 2.00 | K/W |
| R_{thj-a} | Thermal resistance junction to ambient | in free air | | 60 | - | K/W |

LIMITING VALUE

Limiting values in accordance with the Maximum System(IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT | |
|--------------|--|---|----------------------|------|----------------------|------------------------|
| $I_{T(RMS)}$ | RMS on-state current | full sine wave; $T_{mb} \leq 102\text{ }^{\circ}\text{C}$ | - | 16 | A | |
| | Non-repetitive peak on-state current | full sine wave; $T_j = 25\text{ }^{\circ}\text{C}$ prior to surge | $t = 20\text{ ms}$ | - | 120 | A |
| | | | $t = 16.7\text{ ms}$ | - | 140 | A |
| I^2t | I^2t for fusing | $t = 10\text{ ms}$ | - | 45 | A^2s | |
| di_T/dt | Repetitive rate of rise of on-state current after triggering | $I_{TM} = 16\text{ A}$; $I_G = 0.2\text{ A}$; $DI_G/dt = 0.2\text{ A/s}$ | T2+ G+ | - | 100 | $\text{A}/\mu\text{s}$ |
| | | | T2- G- | - | 100 | $\text{A}/\mu\text{s}$ |
| I_{GM} | Peak gate current | | - | 2 | A | |
| V_{GM} | Peak gate voltage | | - | 8 | V | |
| P_{GM} | Peak gate power | | - | 16 | W | |
| $P_{G(AV)}$ | Average gate power | over any 20 ms period | - | 0.35 | W | |
| T_{stg} | Storage temperature | | -40 | 150 | $^{\circ}\text{C}$ | |
| T_j | Junction temperature | | -40 | 125 | $^{\circ}\text{C}$ | |

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| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT | |
|--------------------------------|--|--|--------|------|------|------|----|
| Static characteristics | | | | | | | |
| I _{GT} | Gate trigger current | V _D = 12 V; I _T = 0.1A | T2+ G+ | | 10 | 25 | mA |
| | | | T2+ G- | | 15 | 25 | mA |
| | | | T2- G- | | 15 | 25 | mA |
| | | | T2- G+ | | 30 | 50 | mA |
| I _L | Latching current | V _D = 12 V; I _{GT} = 0.1A | T2+ G+ | - | 20 | 50 | mA |
| | | | T2+ G- | - | 30 | 80 | mA |
| | | | T2- G- | - | 20 | 50 | mA |
| | | | T2- G+ | | 20 | 50 | mA |
| I _H | Holding current | V _D = 12 V; I _{GT} = 0.15A | - | 20 | 40 | mA | |
| V _T | On-state voltage | I _T = 20A | - | - | 1.85 | V | |
| V _{GT} | Gate trigger voltage | V _D = 12 V; I _T = 0.1A | T2+ G+ | 0.50 | 0.78 | 1.50 | V |
| | | | T2+ G- | 0.50 | 0.70 | 1.50 | VV |
| | | | T2- G- | 0.50 | 0.71 | 1.50 | VV |
| | | | T2- G+ | 0.50 | 0.81 | 2.00 | V |
| Dynamic Characteristics | | | | | | | |
| dV _D /dt | Critical rate of rise of off-state voltage | V _{DM} = 67% V _{DRM(max)} ; T _j = 125 °C; Exponential wave form; gate open circuit | 250 | 500 | - | V/μs | |
| dI _{com} /dt | Critical rate of change of commutating current | V _D = 400 V; T _j = 125 °C I _{T(RMS)} = 4.4A; Commutating dv/dt = 18 V/ s, Without snubber; gate open circuit | 6.50 | - | - | A/ms | |
| dI/dt | Repetitive Critical Rate of Rise of On-State Current | I _{PK} = 50 A; PW = 40 sec; di _G /dt = 200 mA/ sec; f = 60 Hz | - | - | 10 | A/μs | |

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RATINGS AND CHARACTERISTIC CURVES BTA16 800B

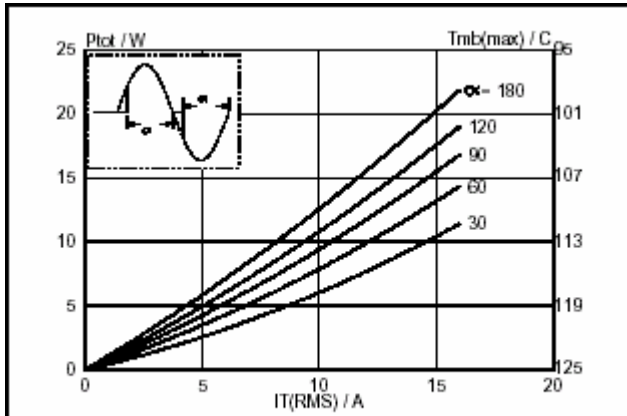


Fig. 1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.

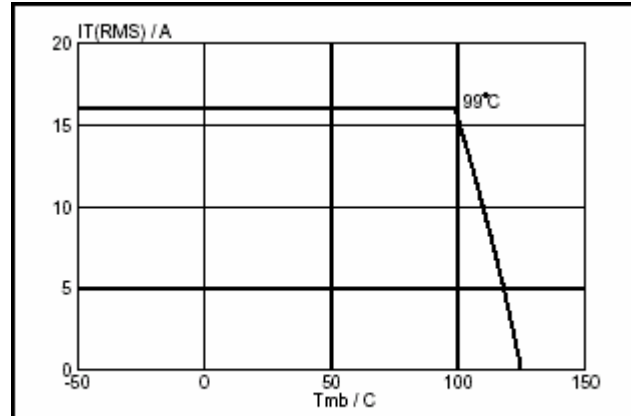


Fig. 4. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .

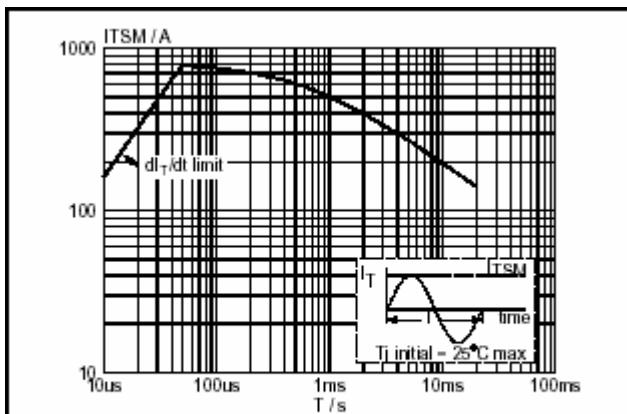


Fig. 2. Maximum permissible non-repetitive peak on-state current I_{TSM} versus pulse width t_p for sinusoidal currents, $t_p \leq 20\text{ms}$.

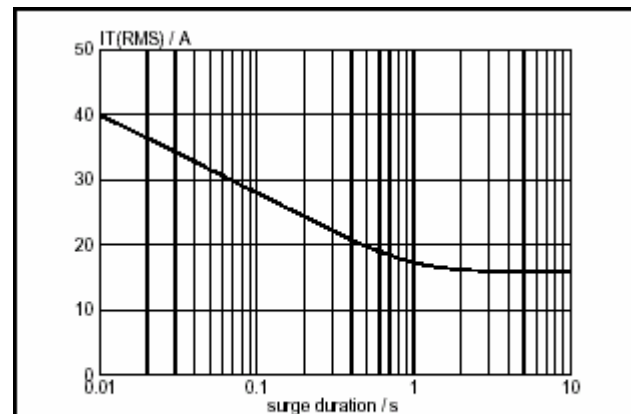


Fig. 5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, $f = 50\text{ Hz}$; $T_{mb} \leq 99^\circ\text{C}$.

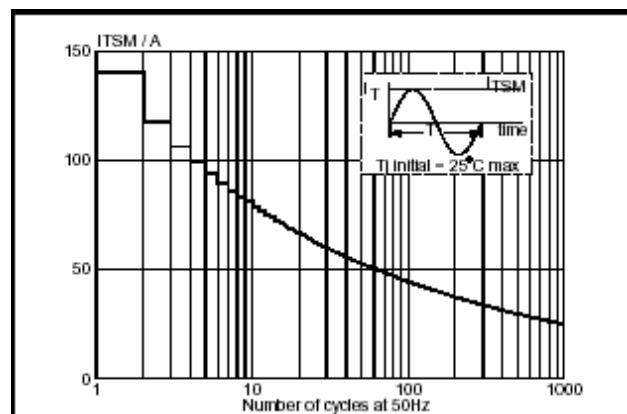


Fig. 3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, $f = 50\text{ Hz}$.

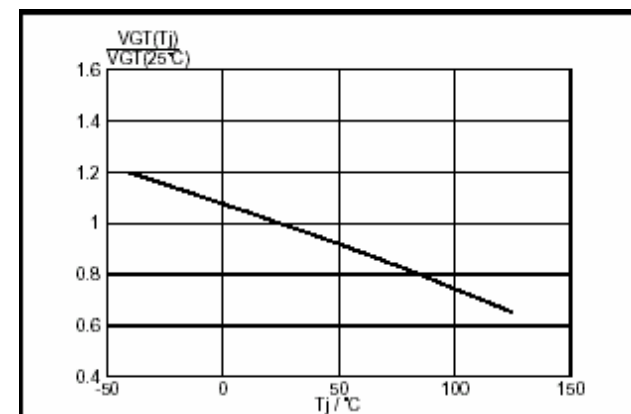
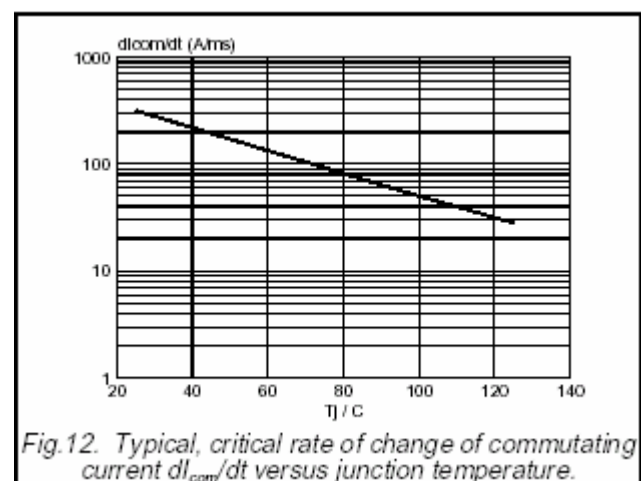
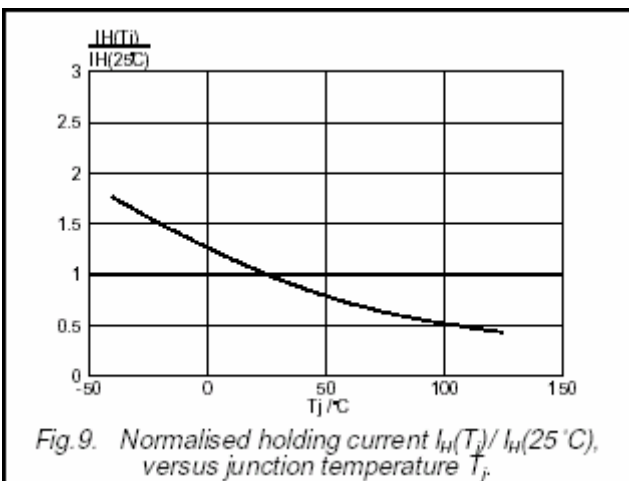
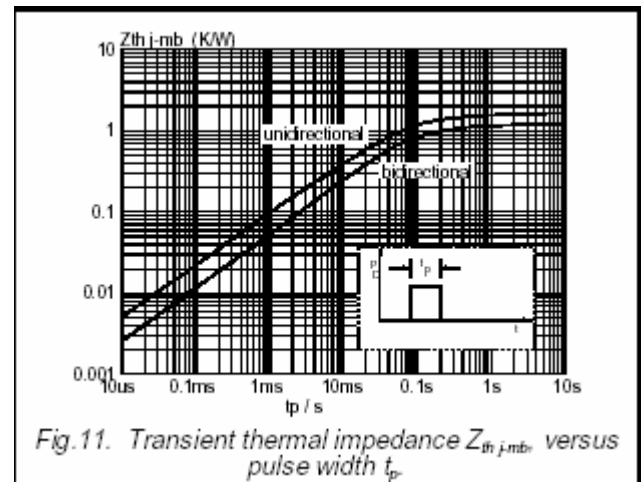
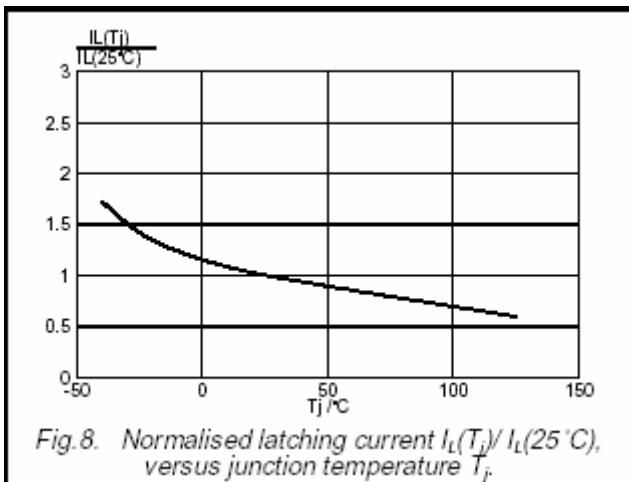
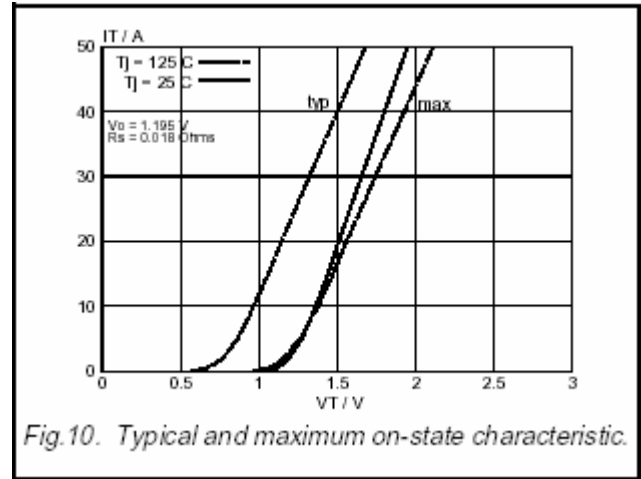
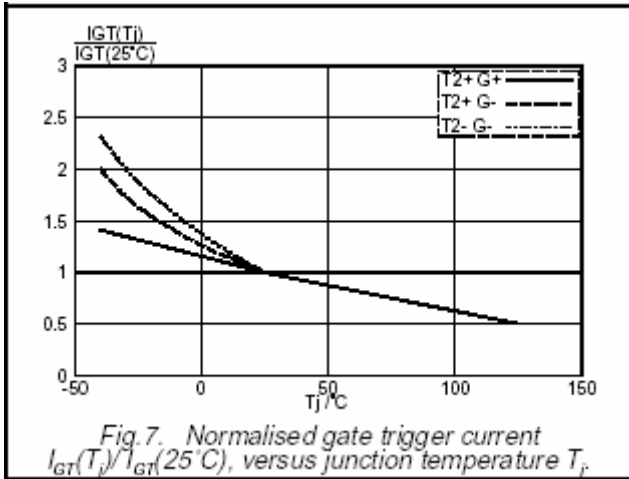


Fig. 6. Normalised gate trigger voltage $V_{GT}(T_j)/V_{GT}(25^\circ\text{C})$, versus junction temperature T_j .

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Note: Specifications are subject to change without notice.

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